

PATENT APPLICATION

Defect Inspection Method

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DEFECT INSPECTION METHOD

BACKGROUND OF THE INVENTION

The present invention relates to a defect inspection method, and in particular to a defect inspection method of semiconductor products that
5 requires defect inspection of high precision.

As the semiconductor design rule becomes finer, the size of manufacturing defects of semiconductor products becomes extremely small. For observation of semiconductor defects, scanning electron
10 microscopes (hereafter referred to as SEMs) have begun to be used besides conventional optical microscopes. However, secondary electrons typically detected in SEMs have a problem that images with edges emphasized are often picked up and defects cannot be necessarily
15 actualized favorably.

Therefore, a technique of detecting reflected electrons together with secondary electrons are detected and detecting a defect by using both detected signals complementarily has begun to be applied. Since
20 reflected electrons emitted from the inspection subject has a directivity, an output correlated with an inclination of a three-dimensional slope in a position of electron beam irradiation is obtained and it can also be utilized for obtaining a defect shape.

25 It is known that the method utilizing

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For example, in a technique disclosed in U.S. Patent

perspective images from a plurality of different

reference positions corresponding to the inspection

the same direction in an inspection position and a

10 maps, and conducting computation on comparison maps.

15 As the method for detecting perspective images, a technique of detecting only electrons emitted from a subject into a certain narrow angle direction by applying an electron beam to an imaging subject is typical.

20 As compared with the case where the angle is
not restricted, the electron detection intensity
becomes small, and consequently the signal-to-noise
ratio of the perspective views is aggravated. When
comparing perspective images picked up in a defect
25 position and a reference position at high
magnification, local perturbation is usually applied in
many cases in order to allow manufacturing tolerance of
non-defective portions. It is now supposed that two

images, i.e., an image 1 and an image 2 are compared
with each other in local perturbation. When an
evaluation pixel in the image 1 is compared with a
reference pixel in the image 2 corresponding thereto, a
5 region corresponding to the manufacturing tolerance
around the reference pixel in the image 2 is set. A
difference between the evaluation pixel value and a
pixel value that is closest to the evaluation pixel
value among all pixels in the set region is outputted
10 as a difference in the inspection pixel between the
image 1 and the image 2.

This algorithm has a problem that when the
signal-to-noise ratios of compared images are poor, a
signal component of an obtained output image remarkably
15 lowers. Because of this problem, there is a tendency
to overlook minute defects in a high magnification
state.

SUMMARY OF THE INVENTION

The problem of the conventional technique is
20 solved by a defect inspection method including the
steps of picking up images of a sample from a plurality
of directions, thereby obtaining external appearance
images of an inspection subject region of the sample
picked up from the plurality of directions; picking up
25 images of a comparison subject region designed so as to
originally have an external appearance identical with
that of the inspection subject region of the sample

- from a plurality of directions identical with those of the inspection subject region, thereby obtaining external appearance images of the comparison subject region picked up from the plurality of directions;
- 5 correcting mis-registrations between the external appearance images of the inspection subject region of the sample picked up from the plurality of directions and the external appearance images of the comparison subject region picked up from the plurality of
- 10 directions that respectively correspond to the external appearance images of the inspection subject region picked up from the plurality of directions; and detecting defects of the inspection subject region by using the external appearance images of the inspection
- 15 subject region of the sample picked up from the plurality of directions and the external appearance images of the comparison subject region picked up from the plurality of directions corrected in mis-registration.
- 20 Other objects, features and advantages of the invention will become apparent from the following description of the embodiments of the invention taken in conjunction with the accompanying drawings.

BRIEF DESCRIPTION OF THE DRAWINGS

- 25 Fig. 1 is a basic configuration diagram of an embodiment according to the present invention.

Fig. 2 is a diagram showing an image feature

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in an embodiment according to the present invention.

Fig. 3 is a diagram showing an embodiment of a defect extraction method according to the present invention.

5 Fig. 4 is a diagram showing an image feature in an embodiment according to the present invention.

Fig. 5 is a diagram showing a signal-to-noise ratio improving method in defect extraction processing according to the present invention.

10 Fig. 6 is a diagram showing an embodiment of a defect extraction method according to the present invention.

Fig. 7 is a diagram showing an embodiment of an image comparison method according to the present
15 invention.

DESCRIPTION OF THE EMBODIMENTS

The present invention will now be described by referring to Figs. 1 to 7.

Fig. 1 is a block diagram showing a schematic
20 general configuration of a semiconductor defect analysis system that is an embodiment of the present invention. Numeral 101 denotes an inspection subject. Numeral 100 denotes an image pickup unit, which includes basic components 102 to 108 described
25 hereafter. Numeral 102 denotes an electron gun for applying electrons to the inspection subject 101 via an electron scanning unit 103. Numeral 104 denotes a non-

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directional electron detection unit for detecting
secondary electrons and reflected electrons generated
from a sample by irradiation of electrons. Numerals
105 and 106 denote narrow angle electron detection
5 units for detecting secondary electrons and reflected
electrons coming from a certain narrow angle direction
range among secondary electrons and reflected electrons
generated from the sample by irradiation of electrons.
The narrow angle electron detection units 105 and 106
10 are designed so as to be different in narrow angle
electron detection direction range. The electron
scanning unit 103 is controlled by a controller 107 so
that two-dimensional scanning will be conducted with
electrons emitted from the electron gun 102. Numeral
15 108 denotes an image memory for storing outputs of the
detection units 104, 105 and 106. Since two-
dimensional scanning is conducted with electrons by the
electron scanning unit 103, defect images which differ
in property according to the detection unit are stored
20 in the image memory 108.

The property of a narrow electron image will
now be described by referring to Fig. 2. Numeral 201
denotes a sectional shape of a defect that has stuck to
the inspection subject. Numeral 202 denotes the
25 electron gun. Numeral 203 denotes the electron
scanning unit. Numeral 204 denotes the electron
detection unit for detecting electrons from a narrow
angle direction. The electron detection unit 204

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detects electrons reflected at the surface of the defect. When the defect surface is perpendicular to a line connecting the defect 201 and the electron detection unit 204, the electron detection unit 204 obtains a strong signal. On the contrary, when the defect surface is in parallel to the line connecting the defect 201 and the electron detection unit 204, the electron detection unit 204 obtains a weak signal. In the case where electrons are detected from opposed directions as represented by 105 and 106 shown in Fig. 1, a slope detected brightly in an image detected by the detection unit 105 is detected darkly by the detection unit 106, and on the contrary a slope detected darkly in an image detected by the detection unit 105 is detected brightly by the detection unit 106. Numeral 205 in Fig. 2 denotes a shadow region of the defect 201. The region 205 is a region having no inclination, but the adjacent defect becomes an obstacle. Since electrons from the surface of the region 205 do not arrive at the electron scanning unit 203 sufficiently, the region 205 is detected darkly.

Owing to the property heretofore described, the inclination of the detection subject can be actualized by using a two-dimensional image formed from a signal obtained by the narrow angle electron detection units. Because of this property, images obtained from detection conducted by the narrow angle electron detection units 105 and 106 are hereafter

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referred to as perspective image 1 and perspective image 2, respectively.

For conducting a review of semiconductor defects, it is necessary to extract defects. A technique for extracting defects most easily is pattern comparison. That is, it becomes possible to identify a region of a defect by comparing the defect with a semiconductor pattern of a non-defective article formed by the same design as that of the position of the defect. In order to implement this, a defect pattern containing a picked-up defect image and a reference pattern containing no defects are preserved in the image memory 108. Each of the defect pattern and the reference pattern is formed of the non-directional electron image, the perspective image 1 and the perspective image 2. Hereafter, sets each having three images are referred to as defect image set and reference image set.

Numeral 109 denotes an image processing unit, which compares a defect image stored in the image memory 108 with a reference image to extract defects. The image memory 108 provided on the image pickup unit 100 and image processing unit 109 may be connected to each other in a hardware manner or may be connected to each other via communication means such as a line. In the case where they are connected via communication means via a line, the image processing unit 109 can be installed at a distance from the image pickup unit 100

having the image memory 108.

Fig. 3 shows defect extraction steps. First, three images obtained from the image pickup units 104, 105 and 106 are mixed by computation (301 and 302) to generate one image. This computation is conducted for each of the defect image set and the reference image set. As a result, two mixed images are calculated. As for the perspective images 1 and 2, it is desirable to obtain a difference. The reason will now be described by referring to Fig. 4. Numeral 401 denotes an inspection subject. Numerals 402 and 403 denote electron detection units installed so as to be opposed to each other. Numeral 404 denotes a region that has become a shadow because the inspection subject 401 itself becomes an obstacle when the detection unit 402 detects electrons and electrons cannot be detected sufficiently. Numeral 405 denotes a region that has become a shadow for the same reason when the detection unit 403 detects electrons. The detection units 402 and 403 detect electrons coming from opposite directions. This results in the following property. Typically, a region detected brightly by the detection unit 402 is detected darkly by the detection unit 403, and on the contrary, a region detected darkly by the detection unit 402 is detected brightly by the detection unit 403. When signals of the detection units 402 and 403 detected in the same position are represented by a two-dimensional vector, distribution

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of this vector in different positions is subject to main component analysis. It will be appreciated that the main component becomes nearly the difference of signals of the regions 402 and 403 because of the
5 above-described property. Therefore, it will be appreciated that it is effective to calculate the difference between the perspective image 1 and the perspective image 2 in order to reduce the loss of information when three images are combined into one
10 image.

One image is calculated from three images by calculating the difference between the perspective images and adding the non-directional electron image to the difference. By thus obtaining one image, it
15 becomes possible to implement registration between the defect image set and the reference image set at a time. In the external view of the inspection subject, there are both portions that are easy to be picked up in a perspective image with high contrast and portions that
20 are easy to be picked up in the non-directional image with high contrast. By combining high information content components of three images, which are different in property, into one image, it is possible to implement registration with higher precision as
25 compared with the case where each image is registered singly.

Subsequently, a mis-registration quantity between the obtained defect image set and the reference

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image set is derived (303). In order to correct the derived mis-registration quantity, image shifts of the reference image set (304 to 306) are conducted.

In addition, in order to make equal in
5 brightness corresponding images between the defect image set and the reference image set corrected in mis-registration, brightness corrections (307 to 309) are conducted.

Successively, in each of the defect image set
10 and the reference image set, a sum image and a difference image of the perspective image 1 and the perspective image 2 are calculated (310 to 313). Between the defect image set and the reference image set, difference images respectively of the sum image
15 and the difference image are calculated by using local perturbation (314 to 316). Pre-dominance of deriving difference images and sum images once and thereafter calculating local perturbation difference images over direct calculating local perturbation difference images
20 of the perspective view 1 and the perspective view 2 of the defect image set and the reference image set will now be described by referring to Fig. 5. The difficulty at the time when extracting defects by using perspective images lies in the fact that signal
25 components are greater than noise components in perspective images. Since the perspective image detector detects only electrons coming from a narrow angle direction range, the signal-to-noise ratio tends

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to fall as compared with the ordinary non-directional electron image.

On the other hand, when defects at high magnification are detected, the pixel size tends to become small with respect to the manufacturing tolerance of the pattern to be inspected. Therefore, a necessity to calculate local perturbation difference image occurs. In the local perturbation difference image calculation, a section of a certain fixed region centering around an inspection pixel is set as a local perturbation region as shown in Fig. 5, a reference pixel that is closest in pixel value to the inspection pixel in this region is specified as a reference pixel corresponding to the inspection pixel. By thus deriving correspondence relations between the inspection image and the reference image every pixel and then subtracting corresponding pixel values, a difference image is generated. As the local perturbation region becomes wide in the local perturbation difference image calculation (314 to 316), the amplitude between the maximum value and the minimum value of noise in the region also becomes large. As a result, there occurs a problem that the difference image signal, i.e., $\Delta A - \Delta B$ in Fig. 5 becomes small.

This problem is improved by increasing the signal-to-noise ratio. Noise superposed on the perspective image 1 and the perspective image 2 can be considered to be white noise. In the case where the

perspective image 1 and the perspective image are
subjected to addition or subtraction, the amplitude is
expected to typically become 1.7 times. On the other
hand, the amplitude of the signal components is nearly
5 doubled by the subtraction as represented by a waveform
406 of Fig. 4. On the contrary, the pixel value of the
slope portion of the subject becomes nearly 0 (zero) as
represented by 405. The influence of noise on the
local perturbation difference appears generally as
10 lowering of the signal strength. In the case where the
inclination of the subject has become nearly 0 (zero)
as a result of addition, demerits caused by lowering of
the signal strength almost disappear. In the case
where subtraction has been conducted, an increase of
15 the signal strength is greater than that of noise, and
consequently the signal-to-noise ratio is increased.
As represented by the waveform 406 after subtraction, a
region extracted in the case where the subtraction has
been conducted includes both the defect portion and its
20 shadow portion.

What is needed as a defect is a region of the
defect itself, and it is not the shadow portion of the
defect. Therefore, it becomes necessary to subtract
the shadow region from the waveform 406. This subject
25 is implemented by subtracting the waveform 405 from the
waveform 406. In the case where this processing is not
conducted, the shadow of the defect is detected
together with the defect. In the embodiment described

by referring to Fig. 3, the method of subtracting the waveform 405 from the waveform 406 has been described. In the case where only detection of an approximate position of the defect is necessary, it is also possible to omit this processing. As processing which needs only detection of an approximate position of the defect, for example, processing of picking up an image of a defect first at low magnification and calculating its approximate position as pre-processing with respect to processing of observing the defect at high magnification can be mentioned. This processing is frequently needed in Review SEMs.

As for the defect and reference non-directional electron images as well, a difference image is calculated by using local perturbation. A resultant difference image 320 and a defect-reference difference image 321 obtained from the perspective images are added up. A resultant sum image is converted to binary values, and defects are extracted. The extracted defects are classified (322) into preset categories according to feature quantities of defects, and a result is displayed (323) on the screen. The classified defect information (324) is stored (325) in a server or the like via a communication line. By the way, higher defect extraction performance can be implemented by providing the non-directional defect-reference difference image 320 and the perspective defect-reference difference image 321 with appropriate

gains before carrying out addition computation. In some inspection subjects, irregular unevenness is present on the surface although the subject has no defects.

5 In perspective images, even small unevenness generates a large signal when the inclination is large. In the inspection subject having unevenness, therefore, a problem of a false report that normal portions are extracted as defects is caused. By making the gain of
10 the non-directional defect-reference difference image 320 larger than the gain of the perspective defect-reference difference image 321 for such inspection subjects, it becomes possible to extract only defects without being affected by minute unevenness of non-
15 defective portions. On the contrary, when minute unevenness as detected, such as micro-scratches often generated after the CMP process in the semiconductor manufacturing process, the gain of the perspective defect-reference difference image 321 is to be made
20 larger than the gain of the non-directional defect-reference difference image 320.

 Although the scheme for extracting defects by utilizing two perspective images has been shown in Fig. 3, it is also possible to detect defects more stably by
25 utilizing more perspective images. For example, it is supposed that there are four perspective images and two perspective images detect electrons in each of mutually contradictory narrow angle direction ranges. In this

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case, it is possible to consider that there are two corresponding sets each including two perspective images. Therefore, it is conceivable to calculate a signal corresponding to the perspective defect-

5 reference difference image 321 of Fig. 3 from each of the sets and calculate a sum of resultant signals. Since noise components can be considered to be non-correlative in each set, it becomes possible to improve the signal-to-noise ratio by calculating the sum.

10 As another method of favorably extracting defects by using perspective images without being affected by minute unevenness, three-dimensional shape comparison can be mentioned. As for a technique for calculating the three-dimensional shape of the
15 inspection subject on the basis of perspective images, for example, the product of the sum image and the difference image of perspective images becomes the inclination. It is possible to derive the three-dimensional shape as integral of the inclination.
20 Application of smoothing filtering on the image obtained as a product of the sum image and the difference image in a direction parallel to a straight line connecting two narrow angle electron detection units can be regarded as an approximate shape change in
25 a section where convolution of the filter is conducted. A resultant image is referred to as shape image. A technique for extracting defects on the basis of a three-dimensional shape is shown in Fig. 6.

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The configuration of Fig. 6 is same as the configuration of Fig. 3 as far as sum images (610 and 612) and difference images (611 and 613) are calculated from perspective images 1 and 2 of a defect image set and perspective images 1 and 2 of a reference image set. However, an inclination of a defect is derived by calculating (614 and 615) the product of the difference image and the sum image. Typically, in the case where the signal-to-noise ratio of an image is poor, the image becomes less susceptible to an influence of inclination dispersion of the local subject and the extraction performance can be improved by lengthening a smoothing section. When the smoothing section is made too long, the image also tends to be more susceptible to an influence of an offset variation or the like of the image between the defect image set and the reference image set. By calculating (619) a difference image of images after being subjected to smoothing processing (615 and 617), height variations are compared between the defect image set and the reference image set. An absolute value thereof and an absolute value of a difference image (618) of the secondary electron image between the defect image set and the reference image set are added up. A resultant image (620) is converted to bi-values (621). As a result, it becomes possible to extract defects.

By deriving a difference between shape images calculated respectively from the defect image set and

the reference image set, stable defect extraction that is not affected by minute unevenness can be implemented. As a matter of course, it is also possible to derive the difference image of the shape image and thereafter adding the difference image of the non-directional electron image. Information of the extracted defects is classified (622) into preset categories according to feature quantities of defects. A result of classification is displayed (623) on the display screen. In addition, the classified defect information (624) is stored (625) in a server via a communication line.

Heretofore, the technique of generating a shape image from two perspective images has been described. It is also possible to form a shape image from more perspective images. For example, as a technique for forming a three-dimensional shape from four perspective images, the technique disclosed in JP-A-1-143127 can be applied.

A technique for generating the difference image will now be described. In the case where the image of the inspection subject is picked up at such a magnification that the pixel size is greater than the size tolerance of the inspection subject as described above, it is necessary to derive an image difference by using local perturbation. This scheme has a problem that defects cannot be extracted in some cases such as the case where a pattern that is to be originally

present is not formed. An example thereof is shown in Fig. 7. In the defect image waveform of Fig. 7, a circuit pattern 701 that is to be originally present is not formed. The defect image waveform always has the same luminance value as a flat waveform 702. In the local perturbation, a pixel having luminance closest to the inspection pixel value in the local perturbation section is derived from the reference image, and the luminance difference is outputted as a difference image pixel value.

In the example of Fig. 7, a pixel having the same pixel value as a defect pixel in a position where a circuit is not formed lies in the local perturbation section. Therefore, a defect that the circuit is not formed is overlooked.

For solving this problem, each of local perturbation based on the defect and local perturbation based on the reference is to be conducted once and a greater output of them is to be outputted as a difference image value.

In the embodiment of Fig. 1, the example in which irradiation and detection of the electron beam are conducted has been described. However, similar processing can also be implemented by using light. As a technique for deriving a three-dimensional inclination of the subject from light, there is a technique described, for example, in "Shape from Shading", Berthold Klaus Paul Horn: Robot Vision, MIT

Press, pp. 243-277. Without losing the generality, the technique described above can be applied intactly.

By applying the defect detection method heretofore described, subtraction and addition are
5 conducted on perspective images each having a poor signal-to-noise ratio every two perspective images. Thus, images each having a high signal-to-noise ratio are generated. In addition, non-directional images each having a high signal-to-noise ratio are also
10 added. As a result, stable defect detection can be implemented.

The invention may be embodied in other specific forms without departing from the spirit or essential characteristics thereof. The present
15 embodiment is therefore to be considered in all respects as illustrative and not restrictive, the scope of the invention being indicated by the appended claims rather than by the foregoing description and all changes which come within the meaning and range of
20 equivalency of the claims are therefore intended to be embraced therein.

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